

Specification for Approval

Date: 2015/09/23

TMDC064EH 2D2MC DTH

Customer: 深圳臺慶

TALTECU DAL

TAI-TECH P/N:	TIMPCUOTOH-ZRZIM	<u> </u>				
CUSTOMER P/N:						
DESCRIPTION:						
QUANTITY:	pcs					
MARK:						
Cı	ustomer Approval Feedba	ack				
	T					
ce Co. Itd						
	CUSTOMER P/N: DESCRIPTION: QUANTITY: IARK:	CUSTOMER P/N: DESCRIPTION: QUANTITY: pcs MARK: Customer Approval Feedba				

□ 西北臺慶科技股份有限公司

TAI-TECH Advanced Electronics Co., Ltd

Headquarter:

NO.1 YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI,

TAO-YUAN HSIEN, TAIWAN, R.O.C.

TEL: +886-3-4641148 FAX: +886-3-4643565 http://www.tai-tech.com.tw

E-mail: sales@tai-tech.com.tw

□ 東莞臺慶精密電子有限公司

DONGGUAN TAI-TECH ADVANCED ELECTRONICS CO., LTD JITIGANG MANAGEMENT DISTRICT, HUANGJIANG, DONGGUAN,

GUANGDONG, CHINA

TEL: +86-769-3365488 FAX: +86-769-3366896

E-mail: sales@tai-tech.net

Office:

金亨國際有限公司

KAMHENG INTERNATIONAL LIMITED

TEL: +86-852-25772033 FAX: +86-852-28817778

□ 臺慶精密電子(昆山)有限公司

 ${\sf TAI-TECH\ ADVANCED\ ELECTRONICS(KUNSHAN)\ CO., LTD\ shinwha\ road,\ kunjia\ hi-tech\ industrial\ park,\ kun-shan,}$

JIANG-SU, CHINA

TEL: +86-512-57619396 FAX: +86-512-57619688

E-mail: sales@tai-tech.cn

Office:

北欣國際有限公司

NORTH STAR INTERNATIONAL LIMITED TEL: +86-512-57619396 FAX: +86-512-57619688

■ 慶邦電子元器件(泗洪)有限公司

TAIPAQ ELECTRONICS (SIHONG) CO., LTD

JIN SHA JIANG ROAD , CONOMIC DEVELOPMENT ZONE SIHONG , JIANGSU , CHINA.

TEL: +86-527-88601191 FAX: +86-527-88601190

E-mail: sales@taipaq.cn

Sales Dep.

APPROVED	CHECKED
曾詩涵	曾詩涵
Angela Tseng	Angela Tseng

R&D Center

APPROVED	CHECKED	DRAWN
楊祥忠	詹偉特	何秦芝
Mike Yang	Jack Chan	Sharon Ho

BTMC76132R2M04 TA734003

SMD Power Choke Coil

TMPC0615H-2R2MG-DTH

	ECN HISTORY LIST								
REV	DATE	DESCRIPTION	APPROVED CHECKED DRAW						
1.0	15/09/23	新 發 行	楊祥忠	詹偉特	何秦芝				
備									
註									

SMD Power Choke Coil

TMPC0615H-2R2MG-DTH

1. Features

- 1. Carbonyl powder inductor.
- 2. Compact design.
- 3. High current , low DCR , high efficiency.
- 4. Very low acoustic noise and very low leakage flux noise.
- 5. High reliability.
- 6. 100% Lead(Pb) & Halogen-Free and RoHS compliant.

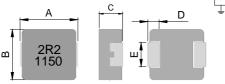




2. Applications

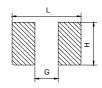
Note PC power system , incl. IMVP-6 DC/DC converter.

3. Dimensions



Series	A(mm) B(mm) C(mm)		C(mm)	D(mm)	E(mm)
TMPC0615H	7.0±0.3	6.6±0.3	1.3±0.2	1.8±0.3	3.0±0.3

Recommend PC Board Pattern



L(mm)	G(mm)	H(mm)
7.7	2.5	3.5

4. Part Numbering



A: Series

B: Dimension BxC

C: Type Carbonyl powder
D: Inductance 2R2=2.2uH
E: Inductance Tolerance M=±20%

F: D/C 印字:黑色; 2R2 及 D/C 1150 (D/C 前二碼是年份,後二碼是週期,依實際生產週期而定)

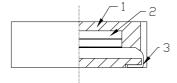
5. Specification

Part Number	Inductance	I rms	I sat	DCR	DCR
	L0 (uH) ±20% @ 0 A	(A) typ.	(A) typ.	(mΩ) typ. @25℃	(mΩ) max. @25℃
TMPC0615H-2R2MG-DTH	2.20	4.5	6.5	48	55

Note:

- 1. Test frequency: L: 100KHz /1.0V
- 2. All test data referenced to 25°C ambient.
- $3. \ \ \mathsf{Testing\ Instrument: L/Q: HP4284A, CH11025, CH3302, CH1320\ , CH1320S\ LCR\ METER\ /\ Rdc: CH16502, Agilent 33420A\ MICRO\ OHMMETER.}$
- 4. Heat Rated Current (Irms) will cause the coil temperature rise approximately $\Delta t \leq$ 40 $^{\circ}$ C (keep 1min.).
- 5. Saturation Current (Isat) will cause L0 $\,$ to drop $\,\leq\,$ 20% typical. (keep quickly).
- 6. The part temperature (ambient + temp rise) should not exceed 125°C under worst case operating conditions. Circuit design, component, PCB trace size and thickness, airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.
- 7. Special inquiries besides the above common used types can be met on your requirement.

6. Material List



NO	Items	Materials	
1	Core	Carbonyl powder or equ.	
2	Wire	Polyester Wire or equivalent.	
3	Solder Plating	100% Pb free solder	

7. Reliability and Test Condition

Item	Performance	Test Condition
Operating temperature	-40~+125℃ (Including self - temperature rise)	
Storage temperature	-40~+125℃ (on board)	
Electrical Performance	Test Test	
Inductance	Defects are dead all attitud above a significant	HP4284A,CH11025,CH3302,CH1320,CH1320S LCR Meter.
DCR	Refer to standard electrical characteristics list.	CH16502,Agilent33420A Micro-Ohm Meter.
Saturation Current (Isat)	△L≦20% typical.	Saturation DC Current (Isat) will cause L0 to drop \triangle L(%)(keep quickly).
Heat Rated Current (Irms)	Approximately △T ≤ 40°C	Heat Rated Current (Irms) will cause the coil temperature rise △T(°C) without core loss. 1. Applied the allowed DC current(keep 1 min.). 2. Temperature measured by digital surface thermometer
Reliability Test		1=
Life Test	Appearance: No damage. Inductance: within±10% of initial value Q: Shall not exceed the specification value.	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Temperature: 125±2°C (Bead) Temperature: 85±2°C (Inductor) Applied current: rated current Duration: 1000±12hrs Measured at room temperature after placing for 24±2 hrs
Load Humidity	RDC : within ±15% of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Humidity: 85±2% R.H, Temperature: 85°C±2°C Duration: 1000hrs Min. with 100% rated current Measured at room temperature after placing for 24±2 hrs
Thermal shock		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Condition for 1 cycle Step1: -40±2°C 30±5min Step2: 25±2°C ≤0.5min Step3: 105±2°C 30±5min Number of cycles: 500 Measured at room temperature after placing for 24±2 hrs
Vibration		Oscillation Frequency: 10 ~ 2K ~ 10Hz for 20 minutes Equipment: Vibration checker Total Amplitude:1.52mm±10% Testing Time: 12 hours(20 minutes, 12 cycles each of 3 orientations)。
Shock		Type Peak value (g's) Normal duration (D) (ms) Wave form (Vi)ft/sec Velocity change (Vi)ft/sec SMD 1500 0.5 Half-sine 15.4 Lead 100 6 Half-sine 12.3
Bending		Shall be mounted on a FR4 substrate of the following dimensions: >=0805:40x100x1.2mm <0805:40x100x0.8mm Bending depth: >=0805:1.2mm <0805:0.8mm duration of 10 sec.

Item	Performance	Test Method and Remarks
Soderability	More than 95% of the terminal electrode should be covered with solder。	Preheat: 150°C,60sec.。 Solder: Sn96.5% Ag3% Cu0.5%。 Temperature: 245±5°C。 Flux for lead free: Rosin. 9.5%。 Dip time: 4±1sec。 Depth: completely cover the termination
Resistance to Soldering Heat		Number of heat cycles: 1 Temperature (°C) Time(s) Temperature ramp/immersion and emersion rate 260 ±5(solder temp) 10 ±1 25mm/s ±6 mm/s
	Appearance: No damage. Inductance: within±10% of initial value Q: Shall not exceed the specification value. RDC: within ±15% of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for 2 times. (IPC/JEDEC J-STD-020DClassification Reflow Profiles With the component mounted on a PCB with the device to be tested, apply a force (>0805:1kg , <=0805:0.5kg)to the side of a device being tested. This force shall be applied for 60 +1 seconds. Also the force shall be applied for 60 +1 seconds. Also the force shall be applied gradually as not to apply a shock to the component being tested.

8. Soldering and Mounting

(1) Soldering

Mildly activated rosin fluxes are preferred. The minimum amount of solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. TAI-TECH terminations are suitable for re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

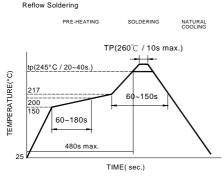
(2) Solder re-flow:

Recommended temperature profiles for re-flow soldering in Figure 1.

(3) Soldering Iron:

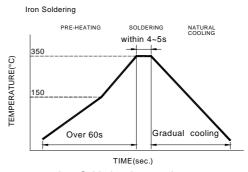
Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

- Preheat circuit and products to 150°C
- Never contact the ceramic with the iron tip
- Use a 20 watt soldering iron with tip diameter of 1.0mm
- 355°C tip temperature (max) 1.0mm tip diameter (max)
- Limit soldering time to 4~5sec.



Reflow times: 3 times max.

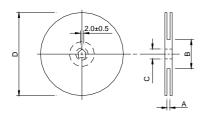
Fig.1

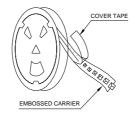


Iron Soldering times: 1 times max.
Fig.2

9. Packaging Information

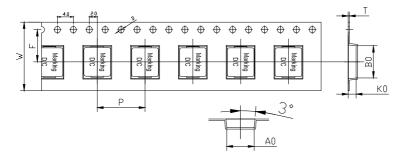
(1) Reel Dimension





Туре	A(mm)	B(mm)	C(mm)	D(mm)
13"x16mm	16.4+2/-0	100±2	13.5±0.5	330

(2) Tape Dimension

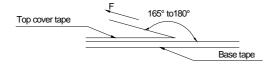


Series	Size	Bo(mm)	Ao(mm)	Ko(mm)	P(mm)	W(mm)	F(mm)	t(mm)	D(mm)
TMPC	0615	7.7±0.1	7.1±0.1	1.8±0.1	12.0±0.1	16±0.3	7.5±0.1	0.35±0.05	1.5±0.1

(3) Packaging Quantity

ТМРС	0615
Chip / Reel	2000
Inner box	4000
Carton	16000

(4) Tearing Off Force



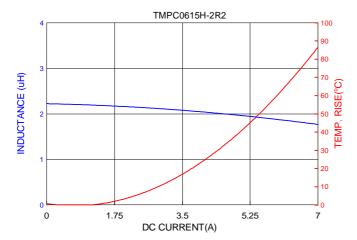
The force for tearing off cover tape is 10 to 130 grams in the arrow direction under the following conditions(referenced ANSI/EIA-481-C-2003 of 4.11 standard).

Room Temp. (℃)	Room Humidity (%)	Room atm (hPa)	Tearing Speed mm/min	
5~35	45~85	860~1060	300	

Application Notice

- Storage Conditions(component level)
- To maintain the solderability of terminal electrodes:
- 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
- 2. Temperature and humidity conditions: Less than 40 $^{\circ}\mathrm{C}$ and 60% RH.
- 3. Recommended products should be used within 12 months form the time of delivery.
- 4. The packaging material should be kept where no chlorine or sulfur exists in the air.
- Transportation
- 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- 2. The use of tweezers or vacuum pick up is strongly recommended for individual components.
- 3. Bulk handling should ensure that abrasion and mechanical shock are minimized.

10. Typical Performance Curves





號碼(No.): CE/2015/13559

日期(Date): 2015/01/27

頁數(Page): 1 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1. YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

(桃園縣中極市中極工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN)

(江蘇省宿達市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

樣品名稱(Sample Description)

: SMD POWER INDUCTOR

樣品型號(Style/Item No.)

TMPB, TMPC, SLPI, SMPI, SMPI-P3, EPI(ePI), VMPI, MLPI SERIES

收件日期(Sample Receiving Date)

: 2015/01/20

測試期間(Testing Period)

: 2015/01/20 TO 2015/01/27

測試結果(Test Results) : 請見下一頁 (Please refer to next pages).

Troy Chang Manager - Tech Signed for and on behalf of SGS TAIWAN LTD. Chemical Laboratory - Taipei

This document is issued by the Company subject to its General Conditions of Service printed overlead, available on request or accessible at his process. Attention is defection from the documents, subject to Terms and Conditions for Electronic Documents at his process of the first process. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained herein reflects the Company's sole responsibility is to its Client and this document does not expensive to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company, Any unauthorized alteration, forgery or falsification of the consent or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



Test Report

號碼(No.): CE/2015/13559 日期(Date): 2015/01/27 頁數(Page): 2 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

(桃園縣中壢市中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN)

(江蘇省宿達市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

測試結果(Test Results)

测试部位(PART NAME)No.1 : 整體混測 (MIXED ALL PARTS)

測試項目 (Test Items)	單位 (Unit)		方法債測 極限値 (MDL)	結果 (Result)
(lest Items)	(Unit)			No.1
缟 / Cadmium (Cd)	mg/kg	參考IEC 62321-5: 2013方法, 以感應 耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
给 / Lead (Pb)	mg/kg	參考IEC 62321-5: 2013方法, 以感應 耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
乘 / Mercury (Hg)	mg/kg	參考IEC 62321-4: 2013方法, 以感應 耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n.d.
六價鉻 / Hexavalent Chromium Cr(VI)	mg/kg	參考IEC 62321: 2008方法, 以UV-VIS 检测. / With reference to IEC 62321: 2008 and performed by UV- VIS.	2	n.d.
绨 / Antimony (Sb)	mg/kg	參考US EPA 3052方法,以感應耦合電 漿原子發射光譜儀檢測。/ With reference to US EPA Method 3052. Analysis was performed by ICP-AES.	2	n.d.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.documents.subject to Terms and Conditions for Electronic Documents at the following the first of the Electronic Documents at the first of the Electronic Documents at the Electronic Document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of client's instruction, if any. The Company's sole responsibility is to its Client and this document does not experted parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approved of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



號碼(No.): CE/2015/13559 日期(Date): 2015/01/27 頁數(Page): 3 of 12

THE RESIDENCE WE WERE THE PROPERTY OF THE PERSON NAMED IN COLUMN

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

(桃園縣中壢市中程工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN)

(江蘇省宿還市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

测试项目	單位	測試方法	方法侦测 極限值	結果 (Result)
(Test Items)	(Unit)	(Method)	(MDL)	No.1
六溴環十二烷及所有主要被辨别出的異構物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	mg/kg	参考IEC 62321: 2008方法,以氣相層析/質譜儀檢測. / With reference to IEC 62321: 2008 method. Analysis was performed by GC/MS.	5	n.d.
鄰苯二甲酸丁苯甲酯 / BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg		50	n.d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	mg/kg	参考IEC 62321-8 (111/321/CD),以氣相層析儀/質譜儀檢測之./ With reference to IEC 62321-8 (111/321/CD). Analysis was performed by GC/MS.	50	n.d.
鄰苯二甲酸二 (2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg		50	n.d.
鄰苯二甲酸二異丁酯 / DIBP (Di- isobutyl phthalate) (CAS No.: 84-69- 5)	mg/kg		50	n.d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761- 40-0; 68515-49-1)	mg/kg		50	n.d.
鄰苯二甲酸二異壬酯 / DINP (Di- isononyl phthalate) (CAS No.: 28553- 12-0: 68515-48-0)	mg/kg		50	n.d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n- octyl phthalate) (CAS No.: 117-84-0)	mg/kg		50	n.d.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at his documents, subject to Terms and Conditions for Electronic Documents at his documents at his documents, subject to Terms and Conditions for Electronic Documents at his document is advantaged. Accordingly, Attention is drawn to the limitation of listinity, indemnification and jurisdiction issues defined therein. Any holder of this document is advantaged that information contained herein reflects the Company's sole responsibility is to its Client and this document does not expected to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company, Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



號碼(No.): CE/2015/13559 日期(Date): 2015/01/27 頁數(Page): 4 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

(桃園縣中總市中總工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN)

(江蘇省宿達市泗洪縣經濟開發區金沙南路-高新枝術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

測試項目	單位	测試方法	方法偵測 極限値	結果 (Result)
(Test Items)	(Unit)	(Method)	(MDL)	No.1
多溴聯苯總和 / Sum of PBBs	mg/kg		-	n.d.
一溴聯苯 / Monobromobiphenyl	mg/kg] [5	n.d.
二溴聯苯 / Dibromobiphenyl	mg/kg] [5	n.d.
三溴聯苯 / Tribromobiphenyl	mg/kg] [5	n.d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg]	5	n.d.
五溴聯苯 / Pentabromobiphenyl	mg/kg] [5	n.d.
六溴聯苯 / Hexabromobiphenyl	mg/kg] [5	n.d.
七溴聯苯 / Heptabromobiphenyl	mg/kg] [5	n.d.
へ溴聯苯 / Octabromobiphenyl	mg/kg	参考IEC 62321: 2008方法,以氣相層 析/質譜儀檢測。/ With reference to IEC 62321: 2008 and performed by GC/MS。	5	n.d.
九溴聯苯 / Nonabromobiphenyl	mg/kg		5	n.d.
十溴聯苯 / Decabromobiphenyl	mg/kg		5	n.d.
多溴聯苯醚總和 / Sum of PBDEs	mg/kg		-	n.d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg		5	n.d.
二溴聯苯醚 / Dibronodiphenyl ether	mg/kg		5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n.d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg] [5	n.d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg] [5	n.d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg	1 [5	n.d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n.d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg		5	n.d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg] [5	n.d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg	7	5	n.d.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at Justine and Conditions for Electronic Documents at Justine and Conditions in Electronic Documents at Justine Electronic Documents at Justine Electronic Documents at Justine Electronic Documents at Justine Electronic Documents and Conditions in Electronic Documents at Justine Electronic Documents and Electronic Documents and



號碼(No.): CE/2015/13559

日期(Date): 2015/01/27 頁數(Page): 5 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺廣精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (沟洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

(桃園蘇中經市中經工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN)

(江蘇省宿達市泗洪縣經濟開發區金沙南路-高新技術產業團 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

測試項目	單位	测試方法	方法侦测 極限値	結果 (Result)
(Test Items) (Un	(Unit)) (Method)	(MDL)	No.1
鹵素 / Halogen				
鹵素 (氣) / Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg		50	n.d.
鹵素 (氣) / Halogen-Chlorine (Cl) (CAS No.: 22537-15-1)	mg/kg	参考BS EN 14582:2007, 以離子層析儀 分析. / With reference to BS EN	50	n.d.
鹵素 (溴) / Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	14582:2007. Analysis was performed by IC.	50	n.d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg		50	n.d.

備註(Note):

- 1. mg/kg = ppm; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未检出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無规格值)
- 5. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個别單一材質的含量。(The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at his provided in the condition of the electronic format documents, subject to Terms and Conditions for Electronic Documents at his document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of client's instruction, and any the Company's sole responsibility is to its Client and this document does not experient to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company, Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



Test Report

號碼(No.): CE/2015/13559

日期(Date): 2015/01/27 頁数(Page): 6 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

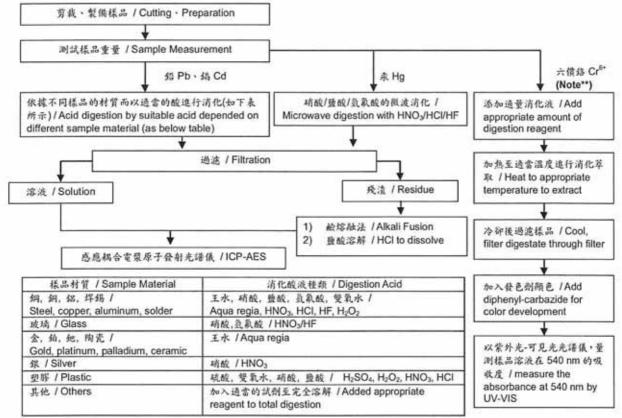
(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園蘇楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市篷胡昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園縣中壢市中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿還市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

- 1) 根據以下的流程關之條件,樣品已完全溶解。(六價格測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr5+ test method excluded)
- 测试人員:楊登律 / Name of the person who made measurement: Climbgreat Yang
- 3) 测试负责人: 张啓典 / Name of the person in charge of measurement: Troy Chang



Note** (For IEC 62321)

- (1) 封對非金易材料加入鹼性消化液, 加热至 90~95℃草取. / For non-metallic material, add alkaline digestion reagent and heat to 90-95℃
- (2) 針對金屬材料加入純水,加熱至沸騰萃取. / For metallic material, add pure water and heat to boiling.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at the subject to Terms and Conditions for Electronic Documents at the subject of the subject to Terms and Conditions for Electronic Documents at the subject of the subject of



號碼(No.): CE/2015/13559 日期(Date): 2015/01/27 頁數(Page): 7 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺磨精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀磐科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

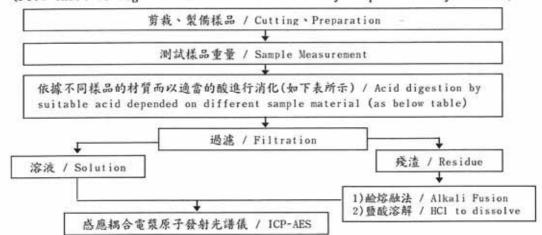
桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY. TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園縣中經市中經工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿還市泗洪縣經濟開發區金沙南路-高新技術產業圖 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

- 1) 根據以下的流程圖之條件,樣品已完全溶解。 / These samples were dissolved totally by pre-conditioning method according to below flow chart.
- 2) 測試人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 3) 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang

元素以 ICP-AES 分析的消化流程圈

(Flow Chart of digestion for the elements analysis performed by ICP-AES)



纲,纲,绍,垾锡 / Steel, copper, aluminum, solder	王水,硝酸,鹽酸,氮氯酸,雙氧水 / Aqua regia, HNOs, HCl, HF, HsOs
玻璃 / Glass	硝酸,氫氰酸 / HNOs/HF
金,銪,宛,陶瓷 / Gold, platinum, palladium, ceramic	王水 / Aqua regia
銀 / Silver	硝酸 / HNOs
型形 / Plastic	硫酸,雙氧水,硝酸,鹽酸 / H:SO1, H:O1, HNO1, HCI
其他 / Others	加入適當的試劑至完全溶解 / Added appropriate reagent to total digestion

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at him for electronic format documents, subject to Terms and Conditions for Electronic Documents at the format of the company and the format of the company and the format of the format of the company and the format of the format of the company and the format of the format of the format of the company and the format of the



Test Report

號碼(No.): CE/2015/13559

日期(Date): 2015/01/27

頁数(Page): 8 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1. YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY,

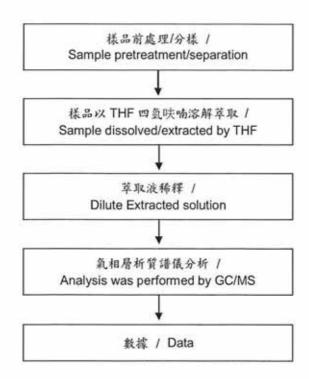
TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園縣中經市中經工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿遼市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

可塑劑分析流程圖 / Analytical flow chart of phthalate content

- 測試人員:徐毓明 / Name of the person who made measurement: Andy Shu
- 测试负责人:張啓興 / Name of the person in charge of measurement: Troy Chang

【測試方法/Test method: IEC 62321-8】



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at humbers of printed overleaf, available on request or accessible at humbers of printed overleaf, and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at humbers of the subject of the document of the advanced representation of the content of the advanced representation of the content of the advanced representation from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company, Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



Test Report

號碼(No.): CE/2015/13559 日期(Date): 2015/01/27 頁數(Page): 9 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

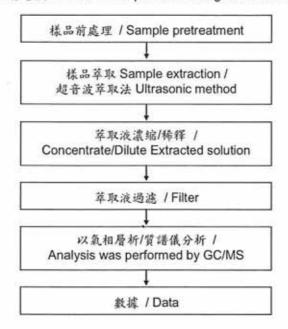
桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1. YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園縣中壢市中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN)

(江蘇省宿還市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

六溴環十二烷分析流程圖 / HBCDD analytical flow chart

- 測試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人: 張啓興 / Name of the person in charge of measurement: Troy Chang



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at his documents, subject to Terms and Conditions for Electronic Documents at his production of the Company Service of Service printed overleaf, and the Imitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's indings at the time of its intervention only and within the limits of client's instruction, if any. The Company's sole responsibility is to its Client and this document does not exconsing all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company, Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlimitful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



Test Report

號碼(No.): CE/2015/13559

日期(Date): 2015/01/27 頁數(Page): 10 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN R. O. C.

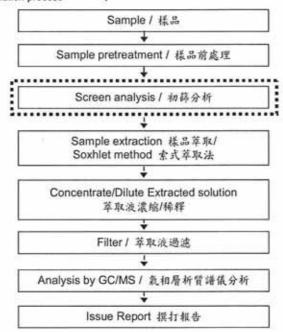
(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園蘇中壢市中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省港市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

- 测試人員: 翁赐彬 / Name of the person who made measurement: Roman Wong
- 测試負责人: 張啓興 / Name of the person in charge of measurement: Troy Chang

初次测试程序 / First testing process -選擇性篩檢程序 / Optional screen process ****

磁認程序 / Confirmation process - · - · ▶



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.np.com/uniteration/conditions for Electronic Documents at http://www.np.com/uniteration/conditions/con



號码(No

號碼(No.): CE/2015/13559

日期(Date): 2015/01/27

頁数(Page): 11 of 12

Test Report

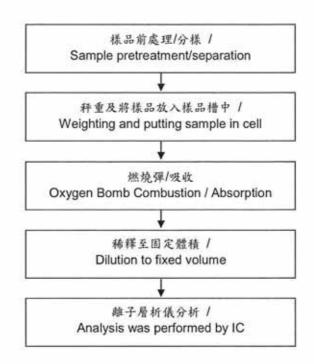
西北臺慶科枝股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.
(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)
(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)
(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園縣中經市中經工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿遼市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

鹵素分析流程圖 / Analytical flow chart of halogen content

- 测试人員: 陳恩臻 / Name of the person who made measurement: Rita Chen
- 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at his processible at his pr



號碼(No.): CE/2015/13559

日期(Date): 2015/01/27 頁數(Page): 12 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

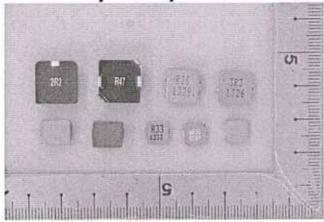
桃園縣楊梅市幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN R. O. C.

(江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園縣中繼市中繼工業區長春六路15號 / NO, 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿達市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD. SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

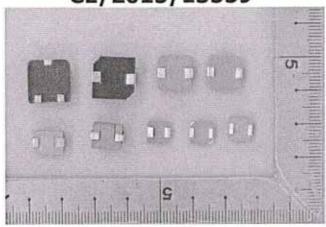
* 照片中如有箭頭標示,則表示爲實際檢測之樣品/部位. *

(The tested sample / part is marked by an arrow if it's shown on the photo.)

CE/2015/13559



CE/2015/13559



** 報告結尾 (End of Report) **

This document is issued by the Company subject to its General Conditions of Service printed overleaf, evailable on request or accessible at http://www.new.company.com